2SC4208, 2SC4208A

Silicon NPN epitaxial planar type

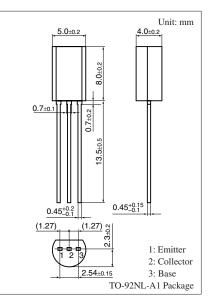
For low-frequency output amplification and driver amplification Complementary to 2SA1619 and 2SA1619A

Features

- \bullet Low collector-emitter saturation voltage $V_{\text{CE}(\text{sat})}$
- Output of 1 W is obtained with a complementary pair with 2SA1619 and 2SA1619A
- Allowing supply with the radial taping

| Parameter | Symbol | Rating | Unit | |
|----------------------------|------------------|------------------|------|---|
| Collector-base voltage | 2SC4208 | V _{CBO} | 30 | V |
| (Emitter open) | 2SC4208A | | 60 | |
| Collector-emitter voltage | 2SC4208 | V _{CEO} | 25 | V |
| (Base open) | 2SC4208A | | 50 | |
| Emitter-base voltage (Coll | V _{EBO} | 7 | V | |
| Collector current | I _C | 500 | mA | |
| Peak collector current | I _{CP} | 1 | А | |
| Collector power dissipatio | P _C | 1 | W | |
| Junction temperature | Tj | 150 | °C | |
| Storage temperature | T _{stg} | -55 to +150 | °C | |

Absolute Maximum Ratings $T_a = 25^{\circ}C$



Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

| Parameter | | Symbol | Conditions | Min | Тур | Max | Unit |
|---------------------------------------|----------|----------------------|--|-----|------|------|------|
| Collector-base voltage | 2SC4208 | V _{CBO} | $I_{C} = 10 \ \mu A, I_{E} = 0$ | 30 | | | V |
| (Emitter open) | 2SC4208A | | | 60 | | | |
| Collector-emitter voltage | 2SC4208 | V _{CEO} | $I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$ | 25 | | | V |
| (Base open) | 2SC4208A | | | 50 | | | |
| Emitter-base voltage (Collector open) | | V _{EBO} | $I_E = 10 \ \mu A, \ I_C = 0$ | 7 | | | V |
| Forward current transfer ratio *1 | | h _{FE1} *2 | $V_{CE} = 10 \text{ V}, \text{ I}_{C} = 150 \text{ mA}$ | 85 | | 340 | |
| | | h _{FE2} | $V_{CE} = 10 \text{ V}, \text{ I}_{C} = 500 \text{ mA}$ | 40 | | | |
| Collector-emitter saturation voltage | | V _{CE(sat)} | $I_{\rm C} = 300 \text{ mA}, I_{\rm B} = 30 \text{ mA}$ | | 0.35 | 0.60 | V |
| Base-emitter saturation voltage | | V _{BE(sat)} | $I_{\rm C} = 300 \text{ mA}, I_{\rm B} = 30 \text{ mA}$ | | 1.1 | 1.5 | V |
| Transition frequency | | f _T | $V_{CB} = 10 \text{ V}, I_E = -50 \text{ mA}, f = 200 \text{ MHz}$ | | 150 | | MHz |
| Collector output capacitance | | C _{ob} | $V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$ | | 6 | 15 | pF |
| (Common base, input open circuited) | | | | | | | |

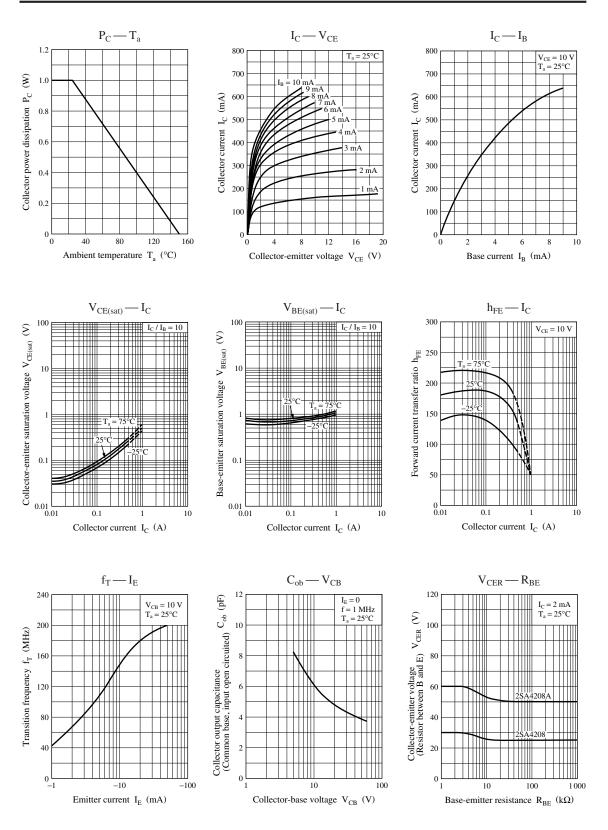
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *1: Pulse measurement

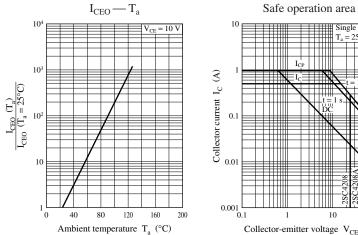
*2: Rank classification

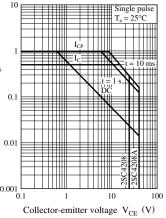
| Rank | Q | R | S | |
|------------------|-----------|------------|------------|--|
| h _{FE1} | 85 to 170 | 120 to 240 | 170 to 340 | |

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